## 74HC393-Q100; 74HCT393-Q100

# Dual 4-bit binary ripple counter Rev. 1 — 19 June 2014

**Product data sheet** 

#### **General description** 1.

The 74HC393-Q100; 7474HCT393-Q100 is a dual 4-stage binary ripple counter. Each counter features a clock input (nCP), an overriding asynchronous master reset input (nMR) and 4 buffered parallel outputs (nQ0 to nQ3). The counter advances on the HIGH-to-LOW transition of nCP. A HIGH on nMR clears the counter stages and forces the outputs LOW, independent of the state of nCP. Inputs include clamp diodes. This enables the use of current limiting resistors to interface inputs to voltages in excess of  $V_{CC}$ .

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### **Features and benefits** 2.

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Input levels:
  - ◆ For 74HC393-Q100: CMOS level
  - For 74HCT393-Q100: TTL level
- Complies with JEDEC standard no. 7A
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - $\bullet$  MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )
- Two 4-bit binary counters with individual clocks
- Divide by any binary module up to 28 in one package
- Two master resets to clear each 4-bit counter individually

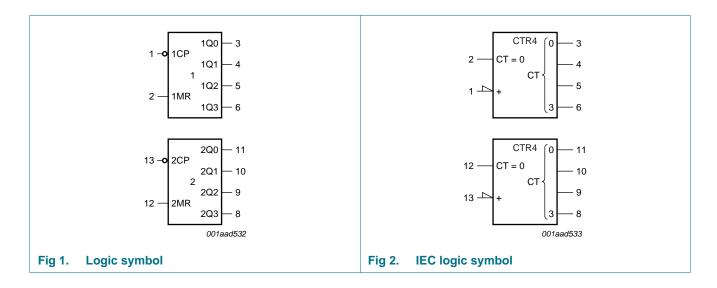


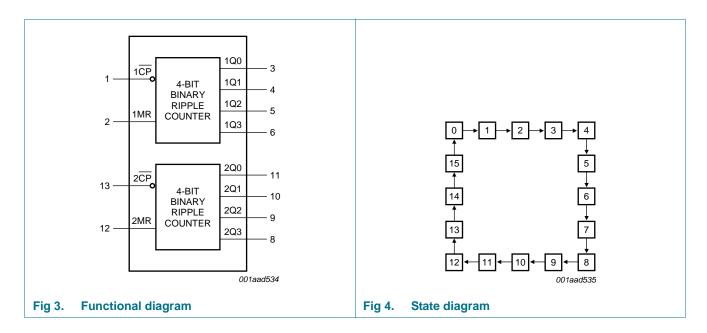
## 3. Ordering information

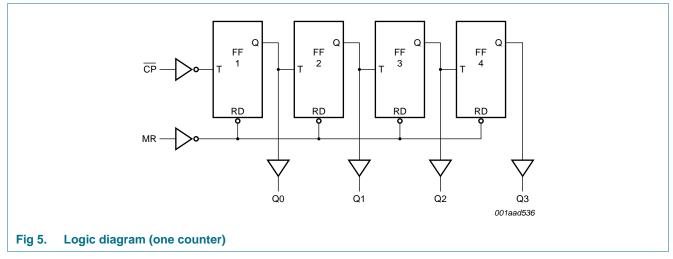
Table 1. Ordering information

| Type number     | Package           |          |  |          |  |  |  |  |  |
|-----------------|-------------------|----------|--|----------|--|--|--|--|--|
|                 | Temperature range | Name     | Version  |          |  |  |  |  |  |
| 74HC393D-Q100   | –40 °C to +125 °C | SO14     | plastic small outline package; 14 leads; body width                                | SOT108-1 |  |  |  |  |  |
| 74HCT393D-Q100  |                   |          | 3.9 mm   |          |  |  |  |  |  |
| 74HC393PW-Q100  | –40 °C to +125 °C | TSSOP14  | plastic thin shrink small outline package; 14 leads;                               | SOT402-1 |  |  |  |  |  |
| 74HCT393PW-Q100 |                   |          | body width 4.4 mm  |          |  |  |  |  |  |
| 74HC393BQ-Q100  | –40 °C to +125 °C | DHVQFN14 | plastic dual in-line compatible thermal enhanced very                              | SOT762-1 |  |  |  |  |  |
| 74HCT393BQ-Q100 |                   |          | thin quad flat package; no leads; 14 terminals; body $2.5 \times 3 \times 0.85$ mm |          |  |  |  |  |  |

## 4. Functional diagram

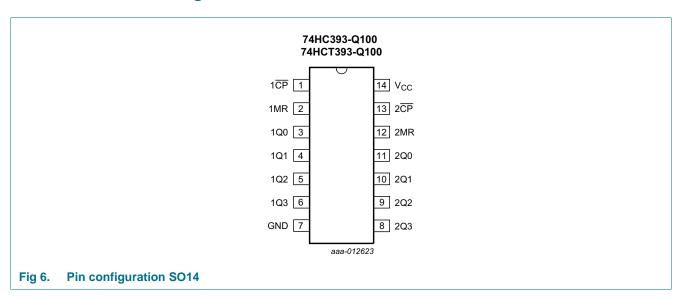


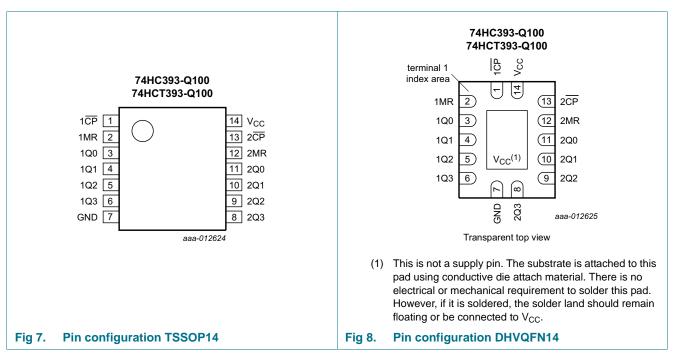




## 5. Pinning information

#### 5.1 Pinning





## 5.2 Pin description

Table 2. Pin description

| Symbol          | Pin | Description                                   |
|-----------------|-----|---|
| 1CP             | 1   | clock input (HIGH-to-LOW, edge-triggered)     |
| 1MR             | 2   | asynchronous master reset input (active HIGH) |
| 1Q0             | 3   | flip-flop output                              |
| 1Q1             | 4   | flip-flop output                              |
| 1Q2             | 5   | flip-flop output                              |
| 1Q3             | 6   | flip-flop output                              |
| GND             | 7   | ground (0 V)                                  |
| 2Q3             | 8   | flip-flop output                              |
| 2Q2             | 9   | flip-flop output                              |
| 2Q1             | 10  | flip-flop output                              |
| 2Q0             | 11  | flip-flop output                              |
| 2MR             | 12  | asynchronous master reset input (active HIGH) |
| 2CP             | 13  | clock input (HIGH-to-LOW, edge-triggered)     |
| V <sub>CC</sub> | 14  | supply voltage                                |

## 6. Functional description

Table 3. Count sequence for one counter [1]

| Count | Output |     |     |     |
|-------|--------|-----|-----|-----|
|       | nQ0    | nQ1 | nQ2 | nQ3 |
| 0     | L      | L   | L   | L   |
| 1     | Н      | L   | L   | L   |
| 2     | L      | Н   | L   | L   |
| 3     | Н      | Н   | L   | L   |
| 4     | L      | L   | Н   | L   |
| 5     | Н      | L   | Н   | L   |
| 6     | L      | Н   | Н   | L   |
| 7     | Н      | Н   | Н   | L   |
| 8     | L      | L   | L   | Н   |
| 9     | Н      | L   | L   | Н   |
| 10    | L      | Н   | L   | Н   |
| 11    | Н      | Н   | L   | Н   |
| 12    | L      | L   | Н   | Н   |
| 13    | Н      | L   | Н   | Н   |
| 14    | L      | Н   | Н   | Н   |
| 15    | Н      | Н   | Н   | Н   |

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level.

## 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol           | Parameter               | Conditions  | Conditions |      |      |    |
|------------------|-------------------------|---|------------|------|------|----|
| V <sub>CC</sub>  | supply voltage          |   |            | -0.5 | +7   | V  |
| I <sub>IK</sub>  | input clamping current  | $V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$ |            | -    | ±20  | mA |
| I <sub>OK</sub>  | output clamping current | $V_{O} < -0.5 \text{ V or } V_{O} > V_{CC} + 0.5 \text{ V}$ |            | -    | ±20  | mA |
| Io               | output current          | $V_{O} = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$         |            | -    | ±25  | mA |
| I <sub>CC</sub>  | supply current          |   |            | -    | ±50  | mA |
| I <sub>GND</sub> | ground current          |   |            | -    | ±50  | mA |
| T <sub>stg</sub> | storage temperature     |   |            | -65  | +150 | °C |
| P <sub>tot</sub> | total power dissipation |   | <u>[1]</u> | -    | 500  | mW |

<sup>[1]</sup> For SO14 package: P<sub>tot</sub> derates linearly with 8 mW/K above 70 °C.
For TSSOP14 packages: P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.
For DHVQFN14 packages: P<sub>tot</sub> derates linearly with 4.5 mW/K above 60 °C.

## **Recommended operating conditions**

Table 5. **Recommended operating conditions** 

Voltages are referenced to GND (ground = 0 V)

| Symbol           | Parameter                           | Conditions              | 74HC393-Q100 |      |          | 74HCT393-Q100 |      |                 | Unit |
|------------------|-------------------------------------|-------------------------|--------------|------|----------|---------------|------|-----------------|------|
|                  |                                     |                         | Min          | Тур  | Max      | Min           | Тур  | Max             |      |
| V <sub>CC</sub>  | supply voltage                      |                         | 2.0          | 5.0  | 6.0      | 4.5           | 5.0  | 5.5             | V    |
| VI               | input voltage                       |                         | 0            | -    | $V_{CC}$ | 0             | -    | V <sub>CC</sub> | V    |
| Vo               | output voltage                      |                         | 0            | -    | $V_{CC}$ | 0             | -    | V <sub>CC</sub> | V    |
| T <sub>amb</sub> | ambient temperature                 |                         | -40          | +25  | +125     | -40           | +25  | +125            | °C   |
| Δt/ΔV            | input transition rise and fall rate | V <sub>CC</sub> = 2.0 V | -            | -    | 625      | -             | -    | -               | ns/V |
|                  |                                     | V <sub>CC</sub> = 4.5 V | -            | 1.67 | 139      | -             | 1.67 | 139             | ns/V |
|                  |                                     | V <sub>CC</sub> = 6.0 V | -            | -    | 83       | -             | -    | -               | ns/V |

#### **Static characteristics**

#### Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol          | Parameter                               | Conditions   |      | 25 °C |      | –40 °C to +85 °C |      | -40 °C to +125 °C |      | Unit |
|-----------------|---|--|------|-------|------|------------------|------|-------------------|------|------|
|                 |   |  | Min  | Тур   | Max  | Min              | Max  | Min               | Max  |      |
| 74HC39          | 3-Q100                                  |  |      |       |      |                  |      | 1                 |      |      |
| $V_{IH}$        | HIGH-level                              | V <sub>CC</sub> = 2.0 V                                      | 1.5  | 1.2   | -    | 1.5              | -    | 1.5               | -    | V    |
|                 | input voltage                           | V <sub>CC</sub> = 4.5 V                                      | 3.15 | 2.4   | -    | 3.15             | -    | 3.15              | -    | V    |
|                 |   | V <sub>CC</sub> = 6.0 V                                      | 4.2  | 3.2   | -    | 4.2              | -    | 4.2               | -    | V    |
| $V_{IL}$        | V <sub>IL</sub> LOW-level input voltage | V <sub>CC</sub> = 2.0 V                                      | -    | 8.0   | 0.5  | -                | 0.5  | -                 | 0.5  | V    |
|                 |   | V <sub>CC</sub> = 4.5 V                                      | -    | 2.1   | 1.35 | -                | 1.35 | -                 | 1.35 | V    |
|                 |   | V <sub>CC</sub> = 6.0 V                                      | -    | 2.8   | 1.8  | -                | 1.8  | -                 | 1.8  | V    |
| V <sub>OH</sub> | HIGH-level                              | $V_I = V_{IH}$ or $V_{IL}$                                   |      |       |      |                  |      |                   |      |      |
|                 | output voltage                          | $I_O = -20 \mu A; V_{CC} = 2.0 V$                            | 1.9  | 2.0   | -    | 1.9              | -    | 1.9               | -    | V    |
|                 |   | $I_O = -20 \mu A; V_{CC} = 4.5 V$                            | 4.4  | 4.5   | -    | 4.4              | -    | 4.4               | -    | V    |
|                 |   | $I_O = -20 \mu A; V_{CC} = 6.0 V$                            | 5.9  | 6.0   | -    | 5.9              | -    | 5.9               | -    | V    |
|                 |   | $I_{O} = -4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$            | 3.98 | 4.32  | -    | 3.84             | -    | 3.7               | -    | V    |
|                 |   | $I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$            | 5.48 | 5.81  | -    | 5.34             | -    | 5.2               | -    | V    |
| $V_{OL}$        | LOW-level                               | $V_I = V_{IH}$ or $V_{IL}$                                   |      |       |      |                  |      |                   |      |      |
|                 | output voltage                          | $I_O = 20 \mu A; V_{CC} = 2.0 V$                             | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                 |   | $I_O = 20 \mu A; V_{CC} = 4.5 V$                             | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                 |   | $I_O = 20 \mu A; V_{CC} = 6.0 \text{ V}$                     | -    | 0     | 0.1  | -                | 0.1  | -                 | 0.1  | V    |
|                 |   | $I_O = 4.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$               | -    | 0.15  | 0.26 | -                | 0.33 | -                 | 0.4  | V    |
|                 |   | $I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$               | -    | 0.16  | 0.26 | -                | 0.33 | -                 | 0.4  | V    |
| I <sub>I</sub>  | input leakage<br>current                | $V_I = V_{CC}$ or GND;<br>$V_{CC} = 6.0 \text{ V}$           | -    | -     | ±0.1 | -                | ±0.1 | -                 | ±0.1 | μΑ   |
| I <sub>CC</sub> | supply current                          | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0 \text{ V}$ | -    | -     | 8.0  | -                | 80   | -                 | 160  | μΑ   |

 Table 6.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol                     | Parameter   | Conditions  |      | 25 °C |      | -40 °C t | o +85 °C | -40 °C to +125 °C |      | Unit |
|----------------------------|---|---|------|-------|------|----------|----------|-------------------|------|------|
|                            |   |   | Min  | Тур   | Max  | Min      | Max      | Min               | Max  |      |
| Cı                         | input<br>capacitance                                  |   | -    | 3.5   | -    |          |          |                   |      | pF   |
| 74HCT3                     | 93-Q100   |   |      |       | '    |          |          |                   |      |      |
| V <sub>IH</sub>            | HIGH-level input voltage                              | V <sub>CC</sub> = 4.5 V to 5.5 V  | 2.0  | 1.6   | -    | 2.0      | -        | 2.0               | -    | V    |
| V <sub>IL</sub>            | LOW-level input voltage                               | V <sub>CC</sub> = 4.5 V to 5.5 V  | -    | 1.2   | 0.8  | -        | 0.8      | -                 | 0.8  | V    |
| V <sub>OH</sub> HIGH-level | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$ |   |      |       |      |          |          |                   |      |      |
|                            | output voltage  | I <sub>O</sub> = -20 μA   | 4.4  | 4.5   | -    | 4.4      | -        | 4.4               | -    | V    |
|                            | $I_O = -6 \text{ mA}$                                 | 3.98  | 4.32 | -     | 3.84 | -        | 3.7      | -                 | V    |      |
| V <sub>OL</sub> LOW-level  |   | $V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$   |      |       |      |          |          |                   |      |      |
|                            | output voltage  | I <sub>O</sub> = 20 μA  | -    | 0     | 0.1  | -        | 0.1      | -                 | 0.1  | V    |
|                            |   | I <sub>O</sub> = 6.0 mA   | -    | 0.15  | 0.26 | -        | 0.33     | -                 | 0.4  | V    |
| I <sub>I</sub>             | input leakage<br>current                              | $V_I = V_{CC}$ or GND;<br>$V_{CC} = 5.5 \text{ V}$  | -    | -     | ±0.1 | -        | ±1.0     | -                 | ±1.0 | μΑ   |
| I <sub>CC</sub>            | supply current  | $V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$  | -    | -     | 8.0  | -        | 80       | -                 | 160  | μΑ   |
| Δl <sub>CC</sub>           | additional supply current                             | $V_I = V_{CC} - 2.1 \text{ V};$<br>other inputs at $V_{CC}$ or GND;<br>$V_{CC} = 4.5 \text{ V}$ to 5.5 V; $I_O = 0 \text{ A}$ |      |       |      |          |          |                   |      |      |
|                            |   | per input pin; nCP  | -    | 40    | 144  | -        | 180      | -                 | 196  | μΑ   |
|                            |   | per input pin; nMR  | -    | 100   | 360  | -        | 450      | -                 | 490  | μΑ   |
| C <sub>I</sub>             | input<br>capacitance                                  |   | -    | 3.5   | -    |          |          |                   |      | pF   |

## 10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); C<sub>L</sub> = 50 pF unless otherwise specified; for test circuit see Figure 11.

| Symbol           | Parameter       | Conditions                                  |     | 25 °C |     | -40 °C | to +85 °C | -40 °C to +125 °C |     | Unit |
|------------------|-----------------|---|-----|-------|-----|--------|-----------|-------------------|-----|------|
|                  |                 |   | Min | Тур   | Max | Min    | Max       | Min               | Max |      |
| 74HC39           | 3-Q100          |   |     |       |     |        |           |                   |     |      |
| t <sub>pd</sub>  | propagation     | nCP to nQ0; see Figure 9                    | 1]  |       |     |        |           |                   |     |      |
|                  | delay           | V <sub>CC</sub> = 2.0 V                     | -   | 41    | 125 | -      | 155       | -                 | 190 | ns   |
|                  |                 | V <sub>CC</sub> = 4.5 V                     | -   | 15    | 25  | -      | 31        | -                 | 38  | ns   |
|                  |                 | $V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$ | -   | 12    | -   | -      | -         | -                 | -   | ns   |
|                  |                 | V <sub>CC</sub> = 6.0 V                     | -   | 12    | 21  | -      | 26        | -                 | 32  | ns   |
|                  |                 | nQx to nQ(x+1); I<br>see Figure 9           | 1]  |       |     |        |           |                   |     |      |
|                  |                 | V <sub>CC</sub> = 2.0 V                     | -   | 14    | 45  | -      | 55        | -                 | 70  | ns   |
|                  |                 | V <sub>CC</sub> = 4.5 V                     | -   | 5     | 9   | -      | 11        | -                 | 14  | ns   |
|                  |                 | $V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$ | -   | 5     | -   | -      | -         | -                 | -   | ns   |
|                  |                 | V <sub>CC</sub> = 6.0 V                     | -   | 4     | 8   | -      | 9         | -                 | 12  | ns   |
| t <sub>PHL</sub> | HIGH to         | nMR to nQx; see Figure 10                   |     |       |     |        |           |                   |     |      |
|                  | LOW propagation | V <sub>CC</sub> = 2.0 V                     | -   | 39    | 140 | -      | 175       | -                 | 210 | ns   |
|                  | delay           | V <sub>CC</sub> = 4.5 V                     | -   | 14    | 28  | -      | 35        | -                 | 42  | ns   |
|                  |                 | $V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$ | -   | 11    | -   | -      | -         | -                 | -   | ns   |
|                  |                 | V <sub>CC</sub> = 6.0 V                     | -   | 11    | 24  | -      | 30        | -                 | 36  | ns   |
| t <sub>t</sub>   | transition      | Qn; see Figure 9                            | 2]  |       |     |        |           |                   |     |      |
|                  | time            | V <sub>CC</sub> = 2.0 V                     | -   | 19    | 75  | -      | 95        | -                 | 110 | ns   |
|                  |                 | V <sub>CC</sub> = 4.5 V                     | -   | 7     | 15  | -      | 19        | -                 | 22  | ns   |
|                  |                 | $V_{CC} = 6.0 \text{ V}$                    | -   | 6     | 13  | -      | 16        | -                 | 19  | ns   |
| t <sub>W</sub>   | pulse width     | nCP HIGH or LOW;<br>see Figure 9            |     |       |     |        |           |                   |     |      |
|                  |                 | V <sub>CC</sub> = 2.0 V                     | 80  | 17    | -   | 100    | -         | 120               | -   | ns   |
|                  |                 | V <sub>CC</sub> = 4.5 V                     | 16  | 6     | -   | 20     | -         | 24                | -   | ns   |
|                  |                 | V <sub>CC</sub> = 6.0 V                     | 14  | 5     | -   | 17     | -         | 20                | -   | ns   |
|                  |                 | nMR HIGH; see Figure 10                     |     |       |     |        |           |                   |     |      |
|                  |                 | V <sub>CC</sub> = 2.0 V                     | 80  | 19    | -   | 100    | -         | 120               | -   | ns   |
|                  |                 | V <sub>CC</sub> = 4.5 V                     | 16  | 7     | -   | 20     | -         | 24                | -   | ns   |
|                  |                 | V <sub>CC</sub> = 6.0 V                     | 14  | 6     | -   | 17     | -         | 20                | -   | ns   |
| t <sub>rec</sub> | recovery        | nMR to nCP; see Figure 10                   |     |       |     |        |           |                   |     |      |
|                  | time            | V <sub>CC</sub> = 2.0 V                     | 5   | 3     | -   | 5      | -         | 5                 | -   | ns   |
|                  |                 | V <sub>CC</sub> = 4.5 V                     | 5   | 1     | -   | 5      | -         | 5                 | -   | ns   |
|                  |                 | V <sub>CC</sub> = 6.0 V                     | 5   | 1     | -   | 5      | -         | 5                 | -   | ns   |

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); C<sub>L</sub> = 50 pF unless otherwise specified; for test circuit see Figure 11.

| Symbol                | Parameter                           | Conditions   |     | 25 °C |     | -40 °C to +85 °C |     | -40 °C to +125 °C |     | Unit |
|-----------------------|-------------------------------------|--|-----|-------|-----|------------------|-----|-------------------|-----|------|
|                       |                                     |  | Min | Тур   | Max | Min              | Max | Min               | Max |      |
| f <sub>clk(max)</sub> | maximum                             | see Figure 9   |     |       |     |                  |     |                   |     |      |
|                       | clock                               | V <sub>CC</sub> = 2.0 V  | 6   | 30    | -   | 5                | -   | 4                 | -   | MHz  |
|                       | frequency                           | V <sub>CC</sub> = 4.5 V  | 30  | 90    | -   | 24               | -   | 20                | -   | MHz  |
|                       |                                     | V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF                              | -   | 99    | -   | -                | -   | -                 | -   | MHz  |
|                       |                                     | V <sub>CC</sub> = 6.0 V  | 35  | 107   | -   | 28               |     | 24                | -   | MHz  |
| $C_{PD}$              | power<br>dissipation<br>capacitance | $C_L = 50 \text{ pF}; f = 1 \text{ MHz};$<br>$V_I = \text{GND to } V_{CC}$ | -   | 23    | -   | -                | -   | -                 | -   | pF   |
| 74HCT3                | 93-Q100                             |  |     |       |     |                  |     |                   |     |      |
| t <sub>pd</sub>       | propagation                         | nCP to nQ0; see Figure 9   |     |       |     |                  |     |                   |     |      |
|                       | delay                               | V <sub>CC</sub> = 4.5 V  | -   | 15    | 25  | -                | 31  | -                 | 38  | ns   |
|                       |                                     | V <sub>CC</sub> = 5 V; C <sub>L</sub> = 15 pF                              | -   | 20    | -   | -                | -   | -                 | -   | ns   |
|                       |                                     | nQx to nQ(x+1); [1] see Figure 9   | !   |       |     |                  |     |                   |     |      |
|                       |                                     | V <sub>CC</sub> = 4.5 V  | -   | 6     | 10  | -                | 13  | -                 | 15  | ns   |
|                       |                                     | $V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$                                | -   | 6     | -   | -                | -   | -                 | -   | ns   |
| t <sub>PHL</sub>      | HIGH to                             | nMR to nQx; see Figure 10  |     |       |     |                  |     |                   |     |      |
|                       | LOW propagation                     | V <sub>CC</sub> = 4.5 V  | -   | 18    | 32  | -                | 40  | -                 | 48  | ns   |
|                       | delay                               | $V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$                                | -   | 15    | -   | -                | -   | -                 | -   | ns   |
| t <sub>t</sub>        | transition                          | Qn; see Figure 9   |     |       |     |                  |     |                   |     |      |
|                       | time                                | V <sub>CC</sub> = 4.5 V  | -   | 7     | 15  | -                | 19  | -                 | 22  | ns   |
| t <sub>W</sub>        | pulse width                         | nCP HIGH or LOW;<br>see Figure 9   |     |       |     |                  |     |                   |     |      |
|                       |                                     | V <sub>CC</sub> = 4.5 V  | 19  | 11    | -   | 24               | -   | 29                | -   | ns   |
|                       |                                     | nMR HIGH; see Figure 10  |     |       |     |                  |     |                   |     |      |
|                       |                                     | V <sub>CC</sub> = 4.5 V  | 16  | 6     | -   | 20               | -   | 24                | -   | ns   |
| t <sub>rec</sub>      | recovery<br>time                    | nMR to nCP;<br>see Figure 10   |     |       |     |                  |     |                   |     |      |
|                       |                                     | V <sub>CC</sub> = 4.5 V  | 5   | 0     | -   | 5                | -   | 5                 | -   | ns   |
| f <sub>clk(max)</sub> | maximum                             | see Figure 9   |     |       |     |                  |     |                   |     |      |
|                       | clock                               | V <sub>CC</sub> = 4.5 V  | 27  | 48    | -   | 22               | -   | 18                | -   | MHz  |
| frequency             |                                     | $V_{CC} = 5 \text{ V}; C_L = 15 \text{ pF}$                                | -   | 53    | -   | -                | -   | -                 | -   | MHz  |

 Table 7.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); C<sub>L</sub> = 50 pF unless otherwise specified; for test circuit see Figure 11.

| Symbol          | Parameter                           | Conditions  | 25 °C |     | -40 °C to +85 °C |     | -40 °C to +125 °C |     | Unit |    |
|-----------------|-------------------------------------|---|-------|-----|------------------|-----|-------------------|-----|------|----|
|                 |                                     |   | Min   | Тур | Max              | Min | Max               | Min | Max  |    |
| C <sub>PD</sub> | power<br>dissipation<br>capacitance | $C_L = 50 \text{ pF; } f = 1 \text{ MHz;}$<br>$V_I = \text{GND to } V_{CC} - 1.5 \text{ V}$ | -     | 25  | -                | -   | -                 | -   | -    | pF |

- [1]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
- [2]  $t_t$  is the same as  $t_{THL}$  and  $t_{TLH}$ .
- [3]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

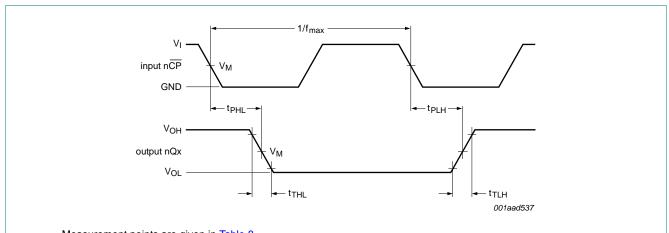
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of outputs.}$ 

#### 10.1 Waveforms



Measurement points are given in Table 8.

Fig 9. Propagation delays clock (nCP) to output (nQx), the output transition times and the maximum clock frequency

Table 8. Measurement points

| Туре          | Input              | Output             |  |
|---------------|--------------------|--------------------|--|
|               | V <sub>M</sub>     | V <sub>M</sub>     |  |
| 74HC393-Q100  | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> |  |
| 74HCT393-Q100 | 1.3 V              | 1.3 V              |  |

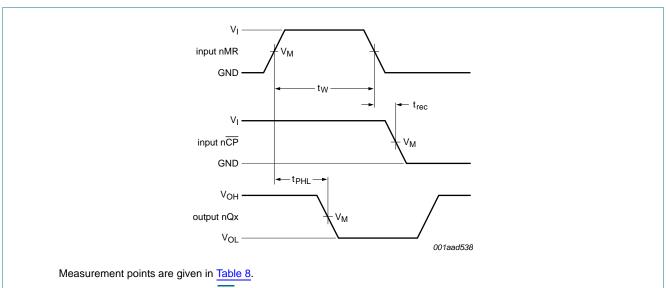
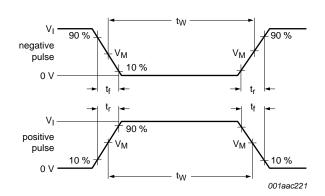
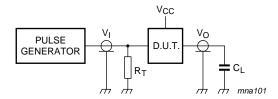


Fig 10. Propagation delays clock (nCP) to output (nQx), pulse width master reset (nMR), and recovery time master reset (nMR) to clock (nCP)



Measurement points are given in Table 8.

a. Input pulse definition



Test data is given in Table 9.

Definitions test circuit:

 $R_{T}$  = Termination resistance should be equal to output impedance  $Z_{o}$  of the pulse generator.

 $C_L$  = Load capacitance including jig and probe capacitance.

b. Test circuit

Fig 11. Test circuit for measuring switching times

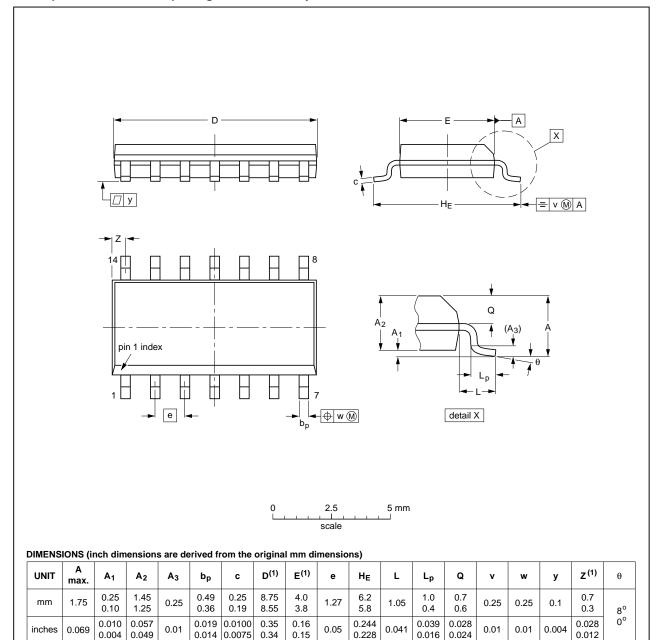
Table 9. Test data

| Туре          | Input           |                                 | Load         |
|---------------|-----------------|---------------------------------|--------------|
|               | VI              | t <sub>r</sub> , t <sub>f</sub> | CL           |
| 74HC393-Q100  | V <sub>CC</sub> | 6 ns                            | 15 pF, 50 pF |
| 74HCT393-Q100 | 3 V             | 6 ns                            | 15 pF, 50 pF |

## 11. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



## Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

| OUTLINE<br>VERSION | REFERENCES |        |       |  | EUROPEAN   | ISSUE DATE                      |
|--------------------|------------|--------|-------|--|------------|---------------------------------|
|                    | IEC        | JEDEC  | JEITA |  | PROJECTION | ISSUE DATE                      |
| SOT108-1           | 076E06     | MS-012 |       |  |            | <del>99-12-27</del><br>03-02-19 |

Fig 12. Package outline SOT108-1 (SO14)

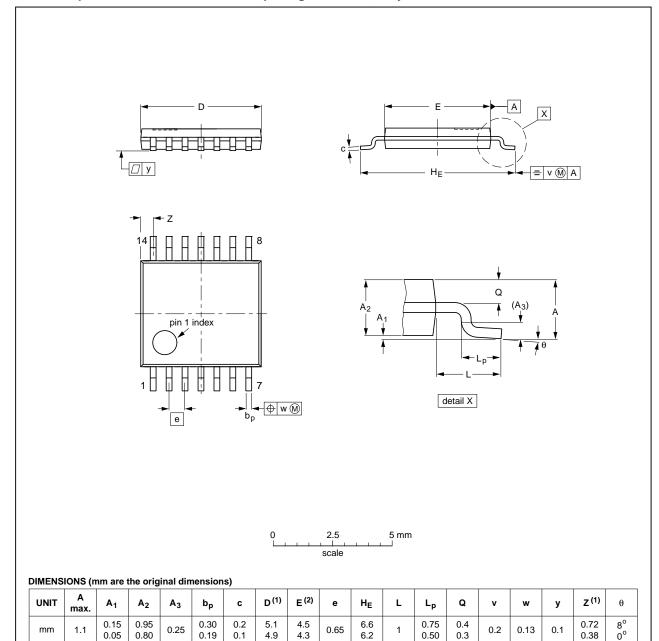
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TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



## Notes

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE  | REFERENCES |        |       |  | EUROPEAN   | ISSUE DATE                      |
|----------|------------|--------|-------|--|------------|---------------------------------|
| VERSION  | IEC        | JEDEC  | JEITA |  | PROJECTION | ISSUE DATE                      |
| SOT402-1 |            | MO-153 |       |  |            | <del>99-12-27</del><br>03-02-18 |

Fig 13. Package outline SOT402-1 (TSSOP14)

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DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1

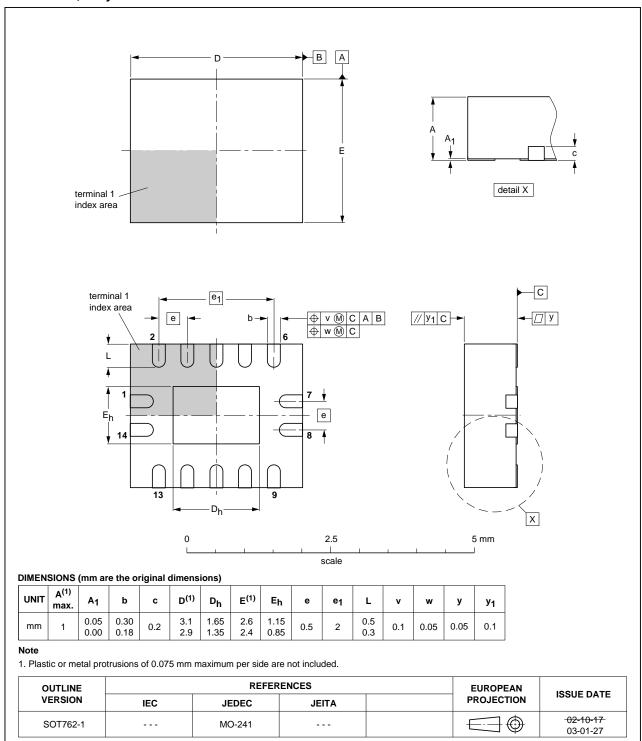


Fig 14. Package outline SOT762-1 (DHVQFN14)

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## 12. Abbreviations

#### Table 10. Abbreviations

| Acronym | Description                             |
|---------|---|
| CMOS    | Complementary Metal-Oxide Semiconductor |
| DUT     | Device Under Test                       |
| ESD     | ElectroStatic Discharge                 |
| HBM     | Human Body Model                        |
| MIL     | Military                                |
| MM      | Machine Model                           |

## 13. Revision history

#### Table 11. Revision history

| Document ID          | Release date | Data sheet status  | Change notice | Supersedes |
|----------------------|--------------|--------------------|---------------|------------|
| 74HC_HCT393_Q100 v.1 | 20140619     | Product data sheet | -             | -          |

#### 14. Legal information

#### 14.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### **Nexperia**

**Dual 4-bit binary ripple counter** 

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